

Fusion-Cast Zirconia Refractory With High Electrical Resistivity.**Specification.****Cross-reference to related applications.**

- 5 [0001] This application claims the benefit under 35 U.S.C. §120 of the filing date of U.S. Provisional Application No. 60/533,990 filed January 2, 2004.

Field of the invention.

- [0002] The present invention relates to fusion-cast zirconia materials, and in particular, to a fusion-cast zirconia refractory having high electrical resistivity suitable for use in glass-melting
10 furnaces.

Description of the related art.

- [0003] Fused refractories comprising primarily ZrO_2 ("zirconia") are traditionally used in glass melting furnaces. The zirconia provides excellent corrosion resistance to the molten glass. Refractories utilizing Al_2O_3 - ZrO_2 - SiO_2 , known as AZS refractories are well known in the art.
15 Such refractories that have a ZrO_2 concentration of 80 wt % or higher are referred to as high-zirconia fused refractories.

- [0004] It is desirable, especially in the production of high-quality glasses, such as TFT-LCD glass and plasma display panels, that the refractory used in the glass melting furnace have high electrical resistivity. It is also generally desirable that the refractory provides superior resistance
20 to corrosion and thermal cycling.

[0005] High-zirconia fused refractories have been disclosed, for example, in U.S. Patent Nos. 5,466,643 to Ishino, et al. (the "643 Patent") and 5,679,612 to Endo, et al. (the "612 Patent"), the entire contents of both of which are hereby incorporated by reference.

- [0006] The '643 Patent discloses a fused zirconia refractory that utilizes 0.05 to 1.0% of P_2O_5 in order to soften the matrix glass. Though this refractory exhibits an acceptable level of electrical resistance, its main objective was to improve the thermal cycling resistance and it does so by increasing the total amount of the glassy phase, which may decrease the corrosion resistance of the refractory.
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- [0007] The '612 Patent discloses a fused zirconia refractory that eliminates the use of P_2O_5 , but adds in 0.05 to 3% of BaO, SrO and MgO in total, in order to reduce the stresses on the glassy phase of the refractory that are caused by the elimination of P_2O_5 . The '612 Patent further discloses the use of Na_2O (in an amount greater than .05%) and K_2O to reduce the tensile stress that is caused by the addition of the alkaline earth metal oxides listed above. The presence of Na_2O and K_2O , in dissimilar amounts, may not provide the most optimized electrical resistance
30 in the refractory.

[0008] Therefore, the present invention seeks to achieve high electrical resistance in the fused Zirconia refractory, while minimizing the concentration of BaO, SrO, MgO, CaO, P_2O_5 , Na_2O and K_2O .
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Summary of the invention.

[0009] In order to achieve the listed objectives, a fusion-cast refractory is provided. The refractory comprises 0.8% to 2.5% Al_2O_3 , 4.0% to 10.0% SiO_2 , 86% to 95% ZrO_2 , 0.1% to 1.2% B_2O_3 , up to 0.04% Na_2O , up to 0.4% CaO , up to 0.1% Fe_2O_3 and up to 0.25% TiO_2 .

5 Detailed description of the preferred embodiments.

[0010] Except where otherwise noted, all percentages listed below, including in any claims, are on a weight basis and are a percentage of the fusion-cast refractory as measured from the pourstream. The present invention is a fusion-cast refractory comprising 0.8% to 2.5% Al_2O_3 , 4.0% to 10.0% SiO_2 , 86% to 95% ZrO_2 , 0.1% to 1.2% B_2O_3 , up to 0.04% Na_2O , up to 0.4% CaO ,
10 up to 0.1% Fe_2O_3 and up to 0.25% TiO_2 . Refractories made in accordance with the present invention are characterized by an electrical resistivity of at least 80 ohm-cm at 1625°C. It is recognized that refractories with lower ZrO_2 content and higher glass content can also be manufactured but that their utility is limited.

[0011] In a preferred embodiment, the present invention is a fusion-cast refractory comprising
15 0.9% to 2.0% Al_2O_3 , 6.0% to 8.0% SiO_2 , 88% to 92% ZrO_2 , 0.3% to 0.9% B_2O_3 , up to 0.04% Na_2O , up to 0.2% CaO , up to 0.05% Fe_2O_3 and up to 0.15% TiO_2 .

[0012] The ZrO_2 content of the refractory according to the invention is 86 to 94%, and preferably is 88 to 94%. ZrO_2 content higher than 94% does not offer crack-free refractories, while ZrO_2 content lower than 86% leads to poor resistance to molten glass.

20 [0013] The SiO_2 content of the refractory according to the invention is 4 to 10%, or preferably 6 to 8%. The glass phase cannot be formed as a continuous matrix phase at a content of less than 4%, while poor resistance to molten glass may be expected at a content of higher than 10%.

[0014] The Al_2O_3 content of the refractory according to the present invention is 0.8 to 2.5%, and
25 preferably 0.9 to 2.0%. Al_2O_3 improves the flowability of the melt at a content higher than 0.8%, but content higher than 2.5% leads to instability of the glass phase, rendering the product prone to failure.

[0015] The B_2O_3 content of the refractory according to the present invention is 0.1 to 1.2%, and is preferably 0.3 to 0.9%. The addition of B_2O_3 aids in suppressing cracks in the refractory
30 during fabrication. This benefit is not realized at a content of less than 0.1%, and concentrations over 1.2% can cause an anomalous behavior of the glassy phase.

[0016] CaO is an optional component of the refractory according to the present invention, and is present in an amount from 0.0 to 0.4% of the refractory. The CaO may be added in order to help reduce the stresses in the refractory and to reduce cracking during fabrication. The
35 addition of CaO is also beneficial when the refractory of the present invention is used in a glass melting furnace where TFT-LCD glass or plasma display panels are formed, as those molten glasses may also contain CaO .

[0017] Na_2O and K_2O are also optional components of the refractory according to the present invention, present in an amount from 0.0 to 0.04% of the refractory. The alkali is a preferably

eliminated from the refractory, as it is the major source of electrical conduction in the glass.

[0018] TiO_2 and Fe_2O_3 may be present as impurities, but their individual concentrations should not exceed 0.25% for the TiO_2 , 0.1% for the Fe_2O_3 , and the total concentration should not exceed 0.35% because they may encourage defect forming potential of the refractory.

5 Examples

[0019] The raw materials include zirconia (derived from zircon sand by removing most of its silica), zircon sand, calcined alumina, boric oxide, calcium carbonate, and dead-burned magnesia. These raw materials are selected such that the impurities (such as Fe_2O_3 , TiO_2 , Na_2O , K_2O) are reduced to a minimum level. The raw materials were carefully weighed and
10 blended into a homogeneous mixture, and subsequently discharged into a large steel crucible for melting. The steel crucible was powered by graphite electrodes using 3 phase current supply. The outside of crucible was cooled by water continuously during the operation.

[0020] The raw materials were melted for one hour and the liquid was poured into a graphite mold. During normal production, this batch process is repeated every hour, 24 hours a day, and
15 up to 7 days a week. The graphite mold was surrounded by calcined alumina powder in a large steel container (known as a bin). After the mold was filled completely, the top of the mold was covered with calcined alumina powder and the bin was stored inside the building for a period of at least 2 weeks to allow the casting to cool slowly. This is important to ensure that the casting is recovered with minimal to no cracking.

[0021] While filling the mold, during pouring of the liquid from the crucible, a small sample of the liquid is collected in a graphite container. The liquid in this container is allowed to cool rapidly. The resulting sample is tested for chemistry using an X-ray Fluorescence Spectrometer. All but one constituents of the zirconia refractory can be analyzed quantitatively using the X-ray Fluorescence Spectrometer. B_2O_3 is analyzed using either Inductively Coupled Plasma
25 Spectrometer (ICP) or DC Arc Emission method. The chemistries of the various samples are listed in the table below.

[0022] The density may be obtained from a small cylindrical core sample, about 25mm in diameter and 100mm long, using Archimedes Water Immersion method, or by weighing the complete casting (after it has been machined to remove the mold skin) and dividing the weight
30 by the casting's external volume.

[0023] The electrical resistivity was measured on a cylindrical sample, 25mm in diameter and 50mm long, using a 4-point electrode assembly. The ends of the sample are coated with platinum ink. Platinum ink was also placed on the circumference of the sample at two places, 25
35 mm apart and 12.5 mm from each end. Platinum wire was then wrapped around under each end of the sample, as well as on the two internal places mentioned above. Current was applied along the ends and voltage drop is measured across the 25mm band in the gauge section described above. Resistivity is measured both using alternating and direct current.

[0024] The microstructure is checked on a series of samples, each about 25mm long by 15mm wide mounted in an epoxy resin and polished to 1micron surface finish. These samples can be

taken from a cylindrical core, typically drilled on a perpendicular through the center of the broadest face of the block so as to represent the average microstructure. Polished sections are typically prepared from regions close to the outside face of the casting as well as its core. The microstructure can be checked using both an Optical microscope and Electron Microscope.

- 5 Identification of crystalline phases is done using an X-ray diffractometer. Glass phase chemistry can be defined using Energy Dispersive Spectrometry (EDS) in the electron microscope. Mean boron content of the glass phase can be estimated by difference of the total analysis from 100%. It can also be more accurately computed from data derived from bulk chemical analysis on powder obtained from the same sample - by ratio with the Silicon content determined by both
- 10 EDS and bulk chemistry methods.

[0025] Resistance to thermal cycling is typically performed on samples, 25mm in diameter by 50mm long, taken from various locations in the casting. The samples are cycled from 1250C to 800C at least 20 times using a controlled heat-up and cool down rate in an electric furnace. Following this test, the change in sample volume can be measured using Water Immersion

15 method. Also, the presence of cracks can be documented using a photograph.

[0026] Examples 4-13 were produced using the method described above. Comparative Examples 1-3 were produced using the same method. The chemical makeup of each example is listed in the table below. The electrical resistivity for each example is also provided in the table below.

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Chemistry (wt%)	1	2	3	4	5	6	7	8	9	10	11	12	13
Al ₂ O ₃	1.06	1	1.11	1.05	0.95	0.89	0.9	1.85	1.61	1.39	1.12	0.96	1.09
SiO ₂	4.76	4.36	5.27	6.63	5.81	6.07	5.82	7.91	7.3	7.06	6.94	7.18	8.77
Fe ₂ O ₃	0.03	0.03	0.03	0.035	0.03	0.03	0.04	0.04	0.03	0.03	0.03	0.03	0.07
TiO ₂	0.1	0.10	0.10	0.11	0.11	0.12	0.12	0.13	0.14	0.13	0.13	0.07	0.08
Na ₂ O	0.033	0.018	0.03	0.012	0.024	0.022	0.02	0.020	0.017	0.030	0.005	0	0
CaO	0.31	0.37	0.29	0.047	0.09	0.179	0.19	0.06	0.057	0.06	0.11	0.05	0.08
MgO	0.2	0.19	0.2	0	0.023	0.05	0.06	0	0	0	0	0	0
B ₂ O ₃	0.27	0.3	0.43	0.88	0.3	0.27	0.28	0.64	0.84	0.86	0.78	0.68	0.58
ZrO ₂	93.2	93.6	92.5	91.2	92.7	92.4	92.6	89.4	90.0	90.4	90.9	91.0	89.3
Bulk Density (g/cc)	5.31	5.21	5.36	5.21	5.36	5.36	5.39	5.24	5.22	5.26	5.32	5.09	4.98
DC Resistivity (ohm-cm) at 1625C	38	55	58	133	104	90	94	98	87	88	101	257	332

[0027] As can be seen, from the standpoint of electrical resistivity, examples 4, 12 and 13 provided the most desirable results. All of the examples 4-13 achieved the desired resistivity of at least 80 ohm-cm. All of the examples were also acceptable in terms of resistance to thermal

25 cycling.

[0028] Obviously, numerous modifications and variations of the present invention are possible. It is, therefore, to be understood that within the scope of the following claims, the invention may be practiced otherwise than as specifically described.